

HT2050 Five LAMP/LED Flash Driver

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Features

- C-MOS Metal-Gate Process
- Operating voltage: 1.2V~4.5V
- Low stand-by current: 1µA at 3V
- A five lamp flash driver
- · Random or sequence flash

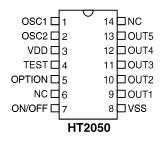
- On/Off toggle control
- 1/10 duty cycle output
- A built-in oscillator
- Minimum external components

General Description

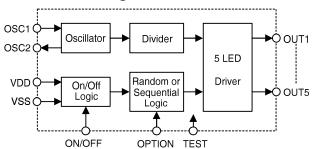
The HT2050 is a low cost, low-power CMOS fabricated LSI chip designed for lamp and LED flash drivers. It contains five flash outputs. Each flash output is with a 10mA capability that can implement random or sequential flash-

ing controlled by a single option pin. The chip requires only one external resistor for normal applications. It is very suitable for use in products that require flashing lights, such as gift cards, Christmas decoration, etc.

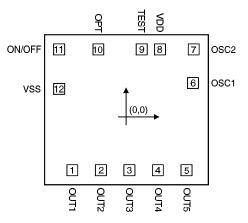
Pin Assignment



Block Diagram



Pad Coordinates



Unit: mil

Pad No. X		Y	Pad No.	X	Y	
1	-21.09	-20.9	7	26.55	26.5	
2	-9.89	-20.9	8	13.35	26.5	
3	1.31	-20.9	9	6.15	26.5	
4	12.51	-20.9	10	-10.89	26.5	
5	23.71	-20.9	11	-26.25	26.5	
6	26.23	13.3	12	-26.25	10.98	

Chip size: $64 \times 59 \text{ (mil)}^2$

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^{*} The IC substrate should be connected to VDD in the PCB layout artwork.



Pad Description

Pad No.	Pad Name	I/O	Description		
1	OUT1	О	Lamp/LED flash drive output		
2	OUT2	О	Lamp/LED flash drive output		
3	OUT3	О	Lamp/LED flash drive output		
4	OUT4	О	Lamp/LED flash drive output		
5	OUT5	О	Lamp/LED flash drive output		
6	OSC1	I	Oscillator input		
7	OSC2	О	Oscillator output		
8	VDD	I	Positive power supply		
9	TEST	I/O	For IC test only		
10	OPTION	I	Random or sequence function selection		
11	ON/OFF	I	Toggle ON/OFF control		
12	VSS	I	Negative power supply, GND		

Note: OPTION=VDD \rightarrow Sequential Mode OPTION=Open \rightarrow Random Mode

Absolute Maximum Ratings

Supply Voltage -0.3V to 5V Storage Temperature $-50^{\circ}C$ to $125^{\circ}C$ Input/Output Voltage ... V_{SS} -0.3V to V_{DD} +0.3V Operating Temperature $0^{\circ}C$ to $70^{\circ}C$

Electrical Characteristics

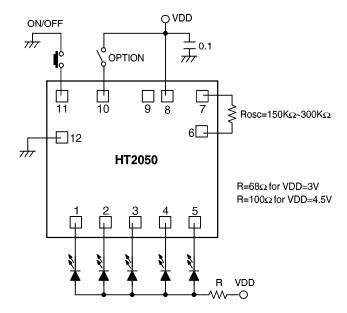
Symbol	Parameter	Test Condition		Min.	Tem	Max.	Unit
	Parameter	V_{DD}	Condition	MIIII.	Тур.	Max.	Ome
V_{DD}	Operating Voltage		_	1.2	3	4.5	V
I _{STB}	Stand-by Current	3V		_	1	2	μΑ
I_{DD}	Operating Current	3V	No load	_	200	500	μΑ
I _{OL}	Output Sink Comment	1.5V	$V_{OL}=0.5V$	5	8	_	mA
	Output Sink Current	3V	V _{OL} =0.5V	10	15	_	mA
Fosc	Oscillator Frequency	_	R=150K~300KΩ	_	64K	_	Hz

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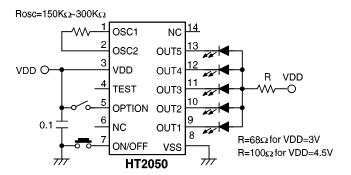


Application Circuit

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